Silicon NPN Epitaxial, Darlington

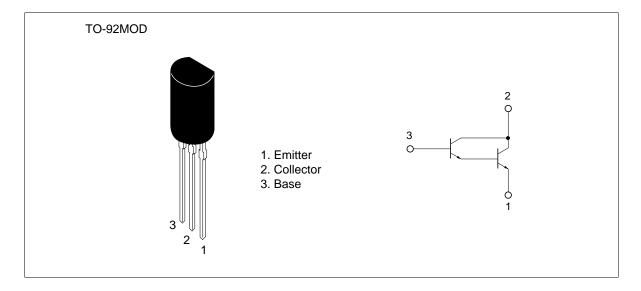
HITACHI

ADE-208-1143 (Z) 1st. Edition Mar. 2001

Application

- Low frequency power amplifier
- Complementary pair with 2SA1193(K)

Outline





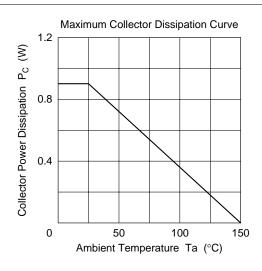
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

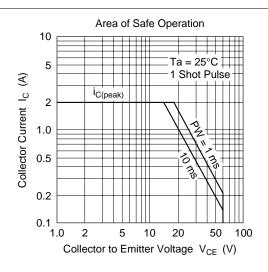
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	60	V
Collector to emitter voltage	V _{CEO}	60	V
Emitter to base voltage	V_{EBO}	7	V
Collector current	I _c	1	Α
Collector peak current	i _{C(peak)}	2	Α
Collector power dissipation	P _c	0.9	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

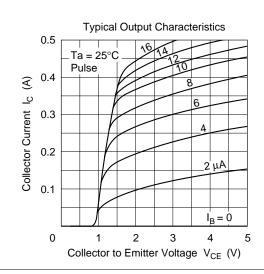
Electrical Characteristics ($Ta = 25^{\circ}C$)

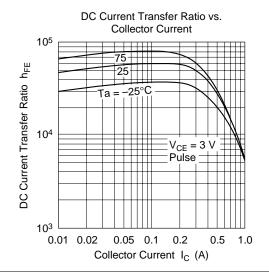
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	60	_	_	V	$I_{\rm C} = 0.1 \text{ mA}, I_{\rm E} = 0$
Collector cutoff current	I _{CEO}	_	_	100	μΑ	V _{CE} = 60 V, R _{BE} = ∞
Emitter cutoff current	I _{EBO}	_	_	100	μΑ	$V_{EB} = 7 \text{ V}, I_{C} = 0$
DC current transfer ratio	h _{FE}	4000	_	_		$V_{CE} = 3 \text{ V}, I_{C} = 0.5 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	1.5	V	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)}$	_	_	2.0	V	$I_{\rm C}$ = 500 mA, $I_{\rm B}$ = 0.5 mA* ¹

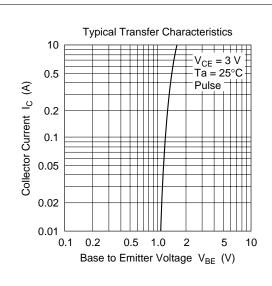
Note: 1. Pulse test

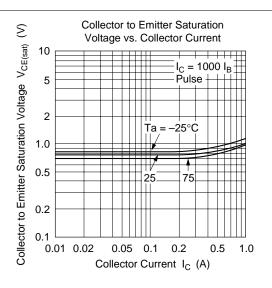


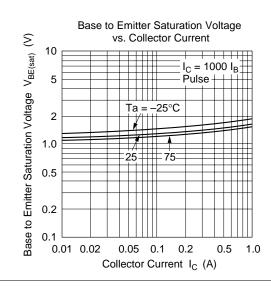




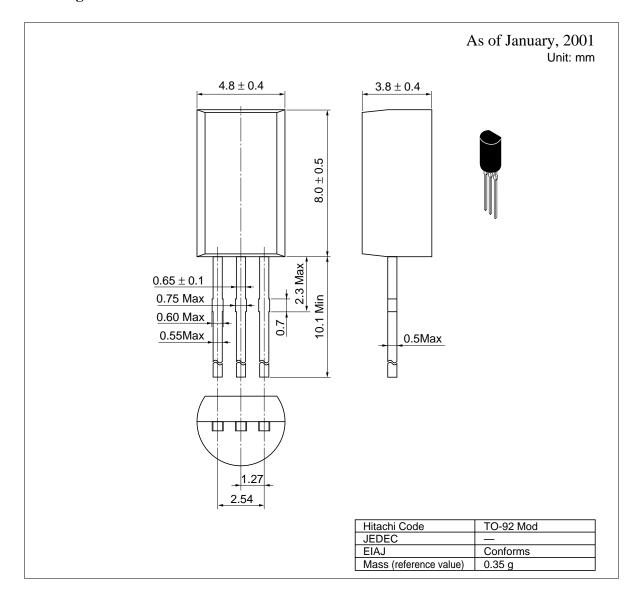








Package Dimensions



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